

XC6228D/H Series

CTR03060-009

300mA High Speed LDO Regulator with ON/OFF Switch

■GENERAL DESCRIPTION

The XC6228D/H series is a high speed LDO regulator that features high accurate, low noise, high ripple rejection, low dropout and low power consumption. The series consists of a voltage reference, an error amplifier, a driver transistor, a current limiter, a phase compensation circuit.

The CE function enables the circuit to be in stand-by mode by inputting low level signal. In the stand-by mode, the series enables the electric charge at the output capacitor CL to be discharged via the internal switch, and as a result the V_{OUT} pin quickly returns to the V_{SS} level. The output stabilization capacitor CL is also compatible with low ESR ceramic capacitors.

The output voltage is selectable from 1.2V, 1.5V, 1.8V, 2.5V, 2.8V, 3.0V, 3.1V, 3.3V which fixed by laser trimming technologies. The over current protection circuit is built-in. This protection circuit will operate when the output current reaches current limit level.

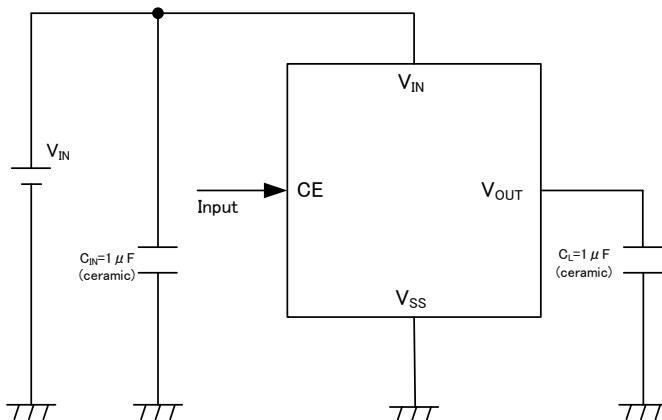
■APPLICATIONS

- Mobile devices
- Wireless communications
- Modules
- Mobile phones

■FEATURES

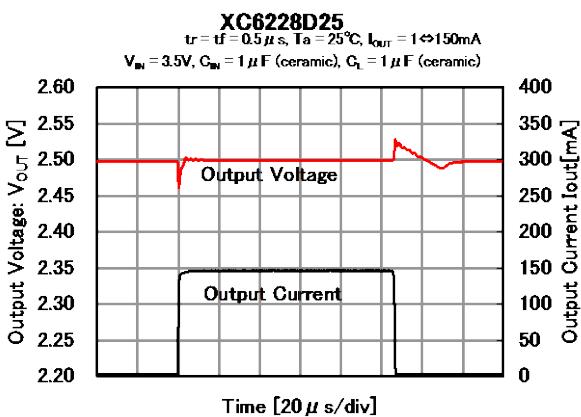
Maximum Output Current	: 300mA
Input Voltage Range	: 1.6V ~ 5.5V
Output Voltages	: 1.2V, 1.5V, 1.8V, 2.5V, 2.8V, 3.0V, 3.1V, 3.3V (±1%, ±2%)
Dropout Voltage	: 200mV@300mA (V _{OUT} =3.0V)
Low Power Consumption	: 100µA
Stand-by Current	: 0.1µA
High Ripple Rejection	: 80dB@1kHz
Protection	: Current Limit (400mA)
Low ESR Capacitors	: C _{IN} =1µF, C _L =1µF
CE Function	: Active High, C _L High Speed Discharge
Operating Ambient Temperature	: -40°C ~ 85°C
Small Package	: SOT-25 USPQ-4B04
Environmentally Friendly	: EU RoHS Compliant, Pb Free

■TYPICAL APPLICATION CIRCUIT

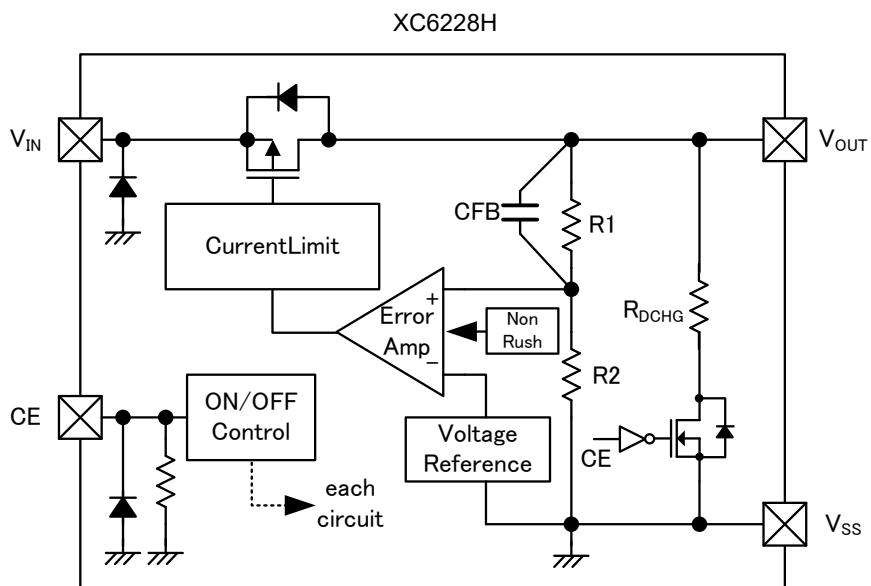
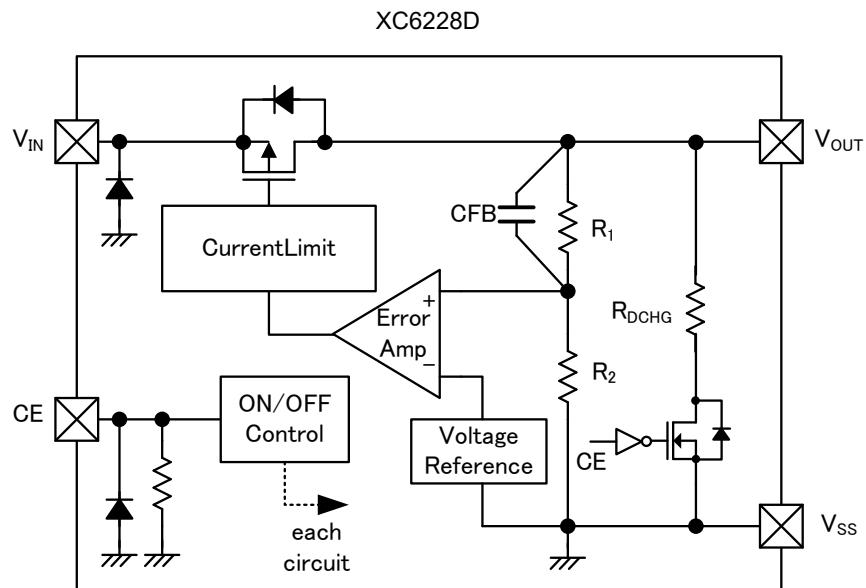


■ TYPICAL PERFORMANCE CHARACTERISTICS

● Load Transient Response



■ BLOCK DIAGRAMS



* Diodes inside the circuits are ESD protection diodes and parasitic diodes.

■ PRODUCT CLASSIFICATION

● Ordering Information

XC6228①②③④⑤⑥-⑦ (*1)

DESIGNATOR	ITEM	SYMBOL	DESCRIPTION
①	Type	D	Without Inrush Current Prevention
		H	With Inrush Current Prevention
②③	Output Voltage	12	1.2V
		15	1.5V
		18	1.8V
		25	2.5V
		28	2.8V
		30	3.0V
		31	3.1V
		33	3.3V
④	Output Voltage Accuracy	1	±1%(*2)
		2	±2%
⑤⑥-⑦ (*1)	Packages (Order Unit)	9R-G	USPQ-4B04 (3,000pcs/Reel)
		VR-G	SOT-25J (3,000pcs/Reel)

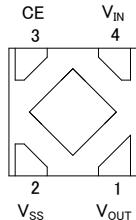
(*1) The “-G” suffix denotes Halogen and Antimony free as well as being fully EU RoHS compliant.

(*2) $V_{OUT(T)} < 2.0V$, $V_{OUT(T)} \pm 20mV$

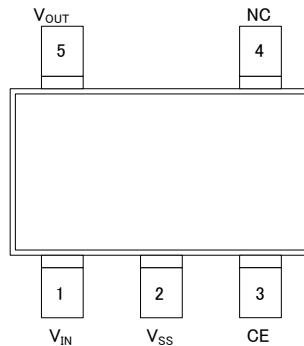
● Selection Guide

TYPE	CURRENT LIMIT	CE PULL-DOWN RESISTOR	C _L DISCHARGE	INRUSH CURRENT PROTECTION
D	Yes	Yes	Yes	No
H	Yes	Yes	Yes	Yes

■ PIN CONFIGURATION



USPQ-4B04
(BOTTOM VIEW)



SOT-25J
(TOP VIEW)

* The dissipation pad for the USPQ-4B04 package should be solder-plated in reference mount pattern and metal masking so as to enhance mounting strength and heat release. If the pad needs to be connected to other pins, it should be connected to the V_{SS} (No. 2) pin.

■ PIN ASSIGNMENT

PIN NUMBER		PIN NAME	FUNCTIONS
USPQ-4B04	SOT-25J		
1	5	V _{OUT}	Output
2	2	V _{SS}	Ground
3	3	CE	ON/OFF Control
4	1	V _{IN}	Power Input
-	4	NC	No Connection

■ PIN FUNCTION ASSIGNMENT

PIN NAME	SIGNAL	STATUS
CE	L	Stand-by
	H	Active
	OPEN	Stand-by*

* An internal pull-down resister maintains the CE pin voltage to be low.

■ ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	RATINGS	UNITS
Input Voltage	V _{IN}	V _{SS} - 0.3 ~ V _{SS} + 7.0	V
Output Current	I _{OUT}	500 (*1)	mA
Output Voltage	V _{OUT}	V _{SS} - 0.3 ~ V _{IN} + 0.3	V
CE Input Voltage	V _{CE}	V _{SS} - 0.3 ~ V _{SS} + 7.0	V
Power Dissipation	SOT-25J	200 (IC only)	mW
		500 (40mm x 40mm Standard board) (*2)	
	USPQ-4B04	100 (IC only)	
		550 (40mm x 40mm Standard board) (*2)	
Operating Ambient Temperature	T _{opr}	-40 ~ 85	°C
Storage Temperature	T _{stg}	-55 ~ 125	°C

(*1) I_{OUT} ≤ Pd / (V_{IN}-V_{OUT})

(*2) The power dissipation figure shown is PCB mounted and is for reference only.

Please refer to PACKAGING INFORMATION for the mounting condition.

ELECTRICAL CHARACTERISTICS

T_a=25°C

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS	CIRCUITS
Output Voltage ($\pm 1\%$)	$V_{OUT(E)}^{(*)1}$	$V_{OUT(T)} \geq 2.0V$, $V_{CE}=V_{IN}$, $I_{OUT}=10mA$	$V_{OUT(T)} \times 0.99^{(*)2}$	$V_{OUT(T)}^{(*)2}$	$V_{OUT(T)} \times 1.01^{(*)2}$	V	①
		$V_{OUT(T)} < 2.0V$, $V_{CE}=V_{IN}$, $I_{OUT} = 10mA^{(*)3}$	$V_{OUT(T)} - 20mV^{(*)2}$	$V_{OUT(T)}^{(*)2}$	$V_{OUT(T)} + 20mV^{(*)2}$	V	
Output Voltage ($\pm 2\%$)	$V_{OUT(E)}^{(*)1}$	$V_{CE}=V_{IN}$, $I_{OUT}=10mA$	$V_{OUT(T)} \times 0.98^{(*)2}$	$V_{OUT(T)}^{(*)2}$	$V_{OUT(T)} \times 1.02^{(*)2}$	V	①
Maximum Output Current	I_{OUTMAX}	$V_{CE}=V_{IN}$	300	-	-	mA	①
Load Regulation	ΔV_{OUT}	$V_{CE}=V_{IN}$, $0.1mA \leq I_{OUT} \leq 300mA$	-	25	45	mV	①
Dropout Voltage	$V_{dif}^{(*)3}$	$V_{CE}=V_{IN}$, $I_{OUT}=300mA$	-	E-1		mV	①
Supply Current	I_{SS}	$V_{CE}=V_{IN}$	-	100	220	μA	②
Stand-by Current	I_{STB}	$V_{CE}=V_{SS}$	-	0.01	0.4	μA	③
Line Regulation	$\Delta V_{OUT}/(\Delta V_{IN} \cdot V_{OUT})$	$V_{OUT(T)} + 0.5V \leq V_{IN} \leq 5.5V$ $V_{CE}=V_{IN}$, $I_{OUT}=50mA$	-	0.01	0.1	%/V	①
Input Voltage	V_{IN}	-	1.6	-	5.5	V	①
Output Voltage Temperature Characteristics	$\Delta V_{OUT}/(\Delta T_{opr} \cdot V_{OUT})$	$V_{CE}=V_{IN}$, $I_{OUT}=10mA$ $-40^{\circ}C \leq T_a \leq 85^{\circ}C$	-	± 100	-	ppm/ $^{\circ}C$	①
Power Supply Rejection Ratio	PSRR	$V_{OUT(T)} < 2.5V$ $V_{IN}=3.0V_{DC}+0.5V_{p-pAC}$ $V_{CE}=V_{OUT(T)}+1.0V$ $I_{OUT}=30mA$, $f=1kHz$	-	80	-	dB	③
		$V_{OUT(T)} \geq 2.5V$ $V_{IN}=[V_{OUT(T)}+1.0]V_{DC}+0.5V_{p-pAC}$ $V_{CE}=V_{OUT(T)}+1.0V$ $I_{OUT}=30mA$, $f=1kHz$					
Current Limit	I_{LIM}	$V_{CE}=V_{IN}$	310	400	-	mA	①
Short Current	I_{SHORT}	$V_{CE}=V_{IN}$, $V_{OUT}=V_{SS}$	-	50	-	mA	①
CE "H" Voltage	V_{CEH}	-	1.0	-	5.5	V	④
CE "L" Voltage	V_{CEL}	-	0	-	0.3	V	④
CE "H" Current	I_{CEH}	$V_{CE}=V_{IN}=5.5V$	3.0	5.5	9.0	μA	④
CE "L" Current	I_{CEL}	$V_{CE}=V_{SS}$	-0.1	-	0.1	μA	④
C_L Discharge Resistance	R_{DCHG}	$V_{IN}=5.5V$, $V_{OUT}=2.0V$, $V_{CE}=V_{SS}$	-	300	-	Ω	①
Inrush Current (Type H)	I_{RUSH}	$V_{IN}=5.5V$, $V_{CE}=0 \rightarrow 5.5V$	-	150	-	mA	⑤

NOTE:

(*)1) $V_{OUT(E)}$: Effective output voltage

(i.e. the output voltage when " $V_{OUT(T)}+1.0V$ " is provided at the V_{IN} pin while maintaining a certain I_{OUT} value.)

(*)2) $V_{OUT(T)}$: Nominal output voltage

(*)3) $V_{dif}=V_{IN1}^{(*)4}-V_{OUT1}^{(*)5}$ ($V_{IN1} \geq 1.6V$)

(*)4) V_{IN1} =The input voltage when V_{OUT1} appears as input voltage is gradually decreased.

(*)5) V_{OUT1} =A voltage equal to 98% of the output voltage whenever an amply stabilized $V_{OUT(T)}+1.0V$ is input for every I_{OUT} .

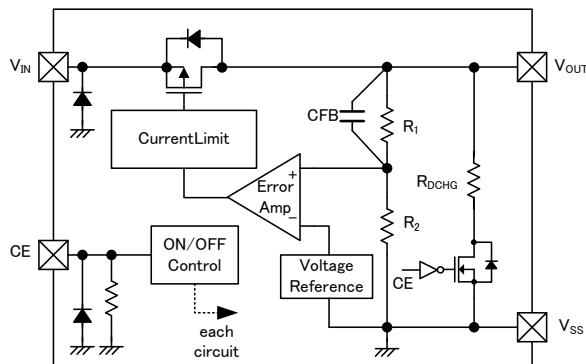
(*)6) Unless otherwise stated regarding input voltage conditions, $V_{IN}=V_{OUT(T)}+1.0V$.

■OUTPUT VOLTAGE CHART

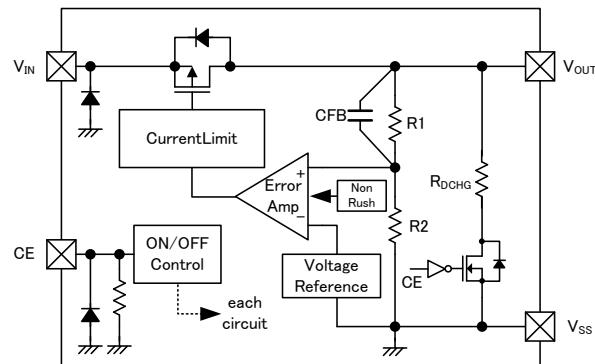
●Voltage Chart 1

NOMINAL OUTPUT VOLTAGE (V)	OUTPUT VOLTAGE($\pm 1\%$) (V)		OUTPUT VOLTAGE($\pm 2\%$) (V)		DROPOUT VOLTAGE (mV) E-1	
V _{OUT(T)}	V _{OUT(E)}		V _{OUT(E)}		V _{dif}	
	MIN.	MAX.	MIN.	MAX.	TYP.	MAX.
1.20	1.180	1.220	1.176	1.224	480	630
1.50	1.480	1.520	1.470	1.530	420	460
1.80	1.780	1.820	1.764	1.836	300	410
2.50	2.475	2.525	2.450	2.550	240	350
2.80	2.772	2.828	2.744	2.856		
3.00	2.970	3.030	2.940	3.060	200	305
3.10	3.069	3.131	3.038	3.162		
3.30	3.267	3.333	3.234	3.366		

■ OPERATIONAL EXPLANATION



XC6228D



XC6228H

The voltage divided by resistors R1 & R2 is compared with the internal reference voltage by the error amplifier. The P-channel MOSFET which is connected to the V_{OUT} pin is then driven by the subsequent output signal. The output voltage at the V_{OUT} pin is controlled and stabilized by a system of negative feedback. The current limit circuit and short circuit protection operate in relation to the level of output current and heat dissipation. Further, the IC's internal circuitry can be shutdown via the CE pin signal.

<Low ESR Capacitor>

The XC6228D/H series needs an output capacitor C_L for phase compensation. Please place an output capacitor (C_L) at the output pin (V_{OUT}) and the ground pin (V_{SS}) as close as possible. Please use the output capacitor (C_L) is 1.0μF or larger. For a stable power input, please connect an input capacitor (C_{IN}) of 1.0μF between the V_{IN} pin and the V_{SS} pin.

<Current Limiter, Short-Circuit Protection>

The XC6228D/H has current limiter and droop shape of fold-back circuit. When the load current reaches the current limit, the droop current limiter circuit operates and the output voltage drops. When the output voltage dropped, the fold-back circuit operates and the output current goes to decrease. The output current finally falls at the level of 50mA when the output pin is short-circuited.

<CE Pin>

The IC's internal circuitry can be shutdown via the signal from the CE pin. In shutdown mode, the XC6228D/H series enables the electric charge at the output capacitor (C_L) to be discharged via the internal switch located between the V_{OUT} and V_{SS} pins, and as a result the V_{OUT} pin quickly returns to the V_{SS} level. The XC6228D/H series has a pull-down resistor at the CE pin inside, so that the CE pin input current flows.

<Inrush Current Protection>

The inrush current protection circuit is built in the XC6228H.

When the IC starts to operate, the protection circuit limits the inrush current from input pin (V_{IN}) to output pin (V_{OUT}) to charge C_L capacitor.

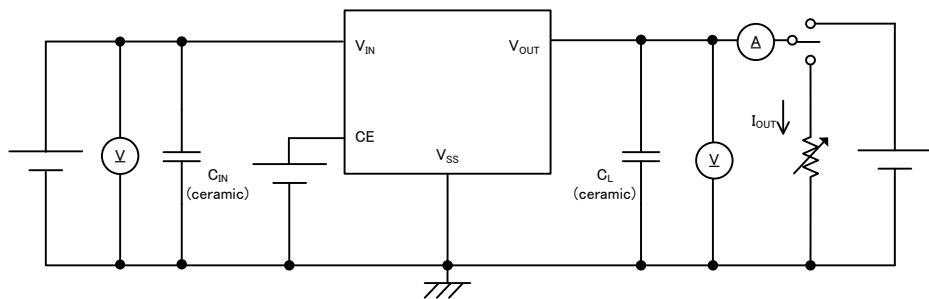
■ NOTES ON USE

1. For temporary, transitional voltage drop or voltage rising phenomenon, the IC is liable to malfunction should the ratings be exceeded.
2. Where wiring impedance is high, operations may become unstable due to the noise and/or phase lag depending on output current. Please strengthen V_{IN} and V_{SS} wiring in particular.
3. The input capacitor C_{IN} and the output capacitor C_L should be placed to the as close as possible with a shorter wiring.
4. The IC is controlled with constant current start-up. Start-up sequence control is requested to draw a load current after even nominal output voltage rising up the output voltage.
5. The CE pin current increases to tens of μA when a voltage higher than the V_{IN} pin voltage is applied to the CE pin. Therefore, if you want to suppress the CE pin current, design the device so that the V_{IN} pin voltage is higher than the CE pin voltage.
6. Torex places an importance on improving our products and its reliability. However, by any possibility, we would request user fail-safe design and post-aging treatment on system or equipment.

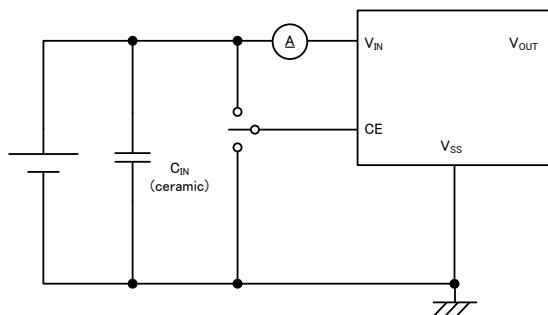
XC6228D/H Series

TEST CIRCUITS

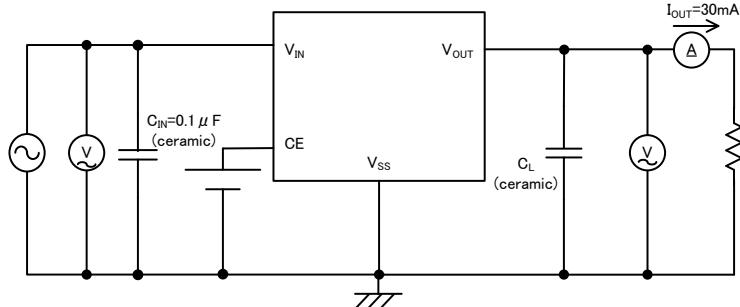
● Circuit ①



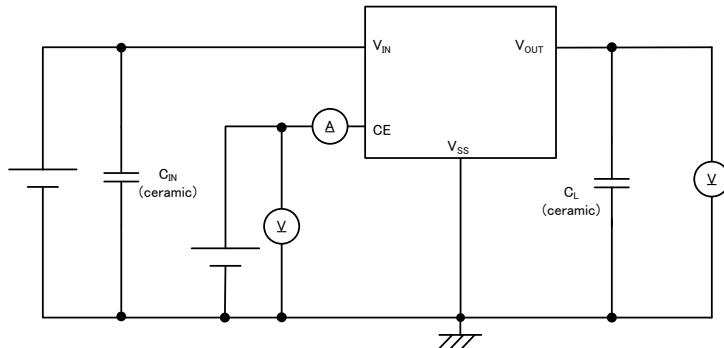
● Circuit ②



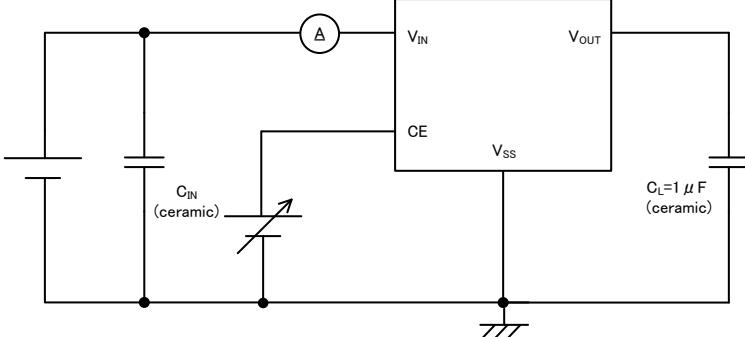
● Circuit ③



● Circuit ④

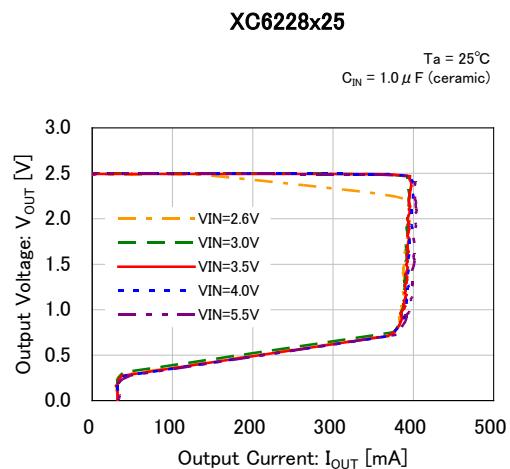
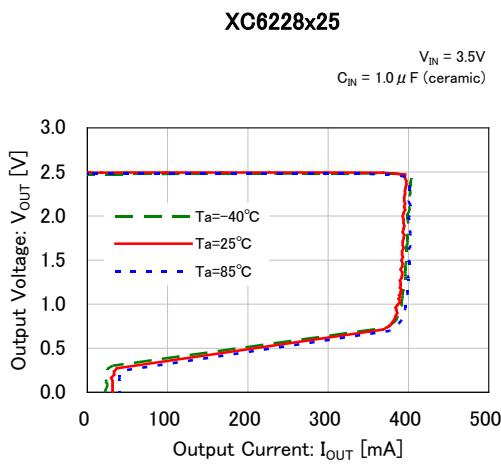
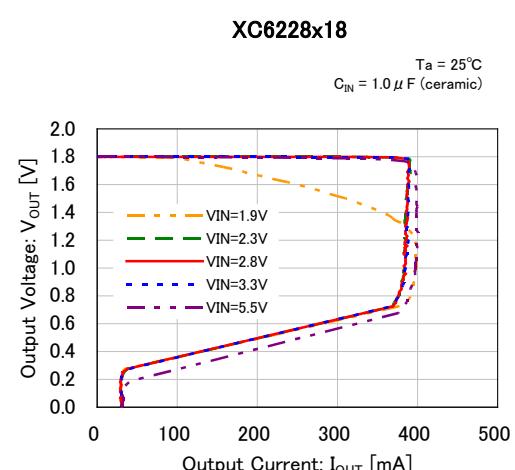
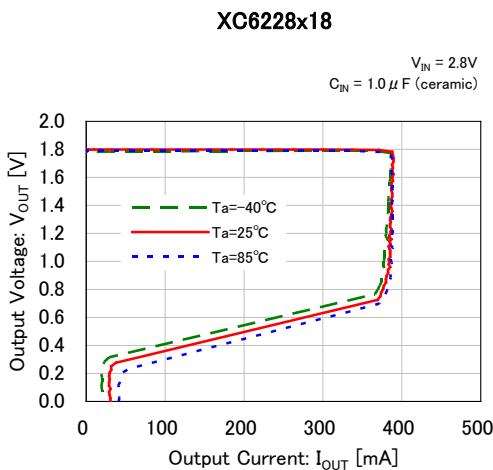
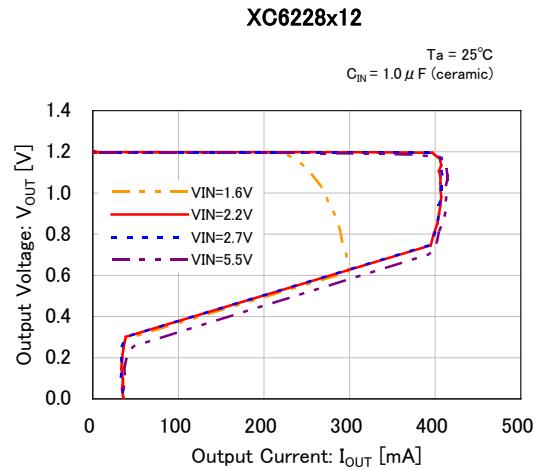
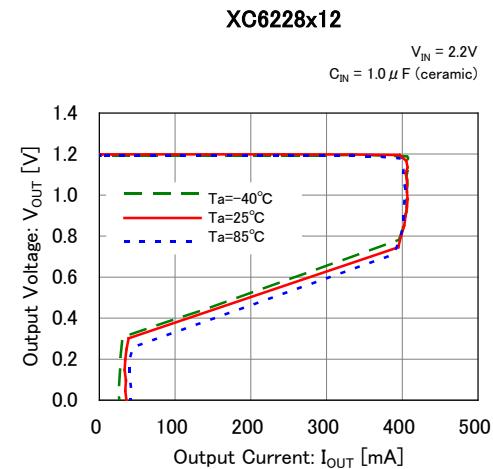


● Circuit ⑤



■ TYPICAL PERFORMANCE CHARACTERISTICS

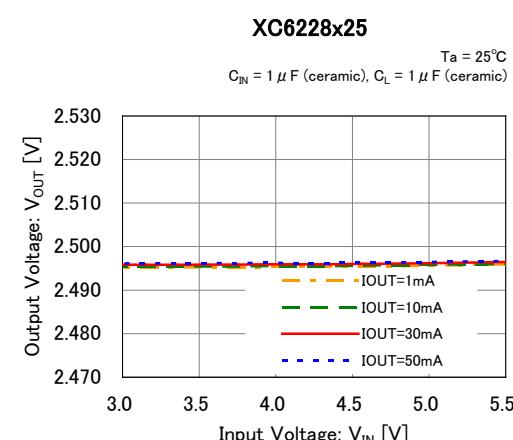
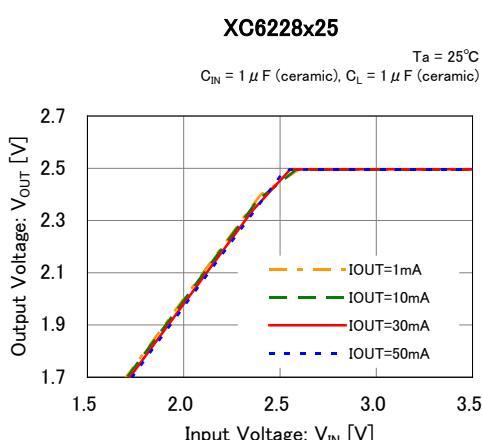
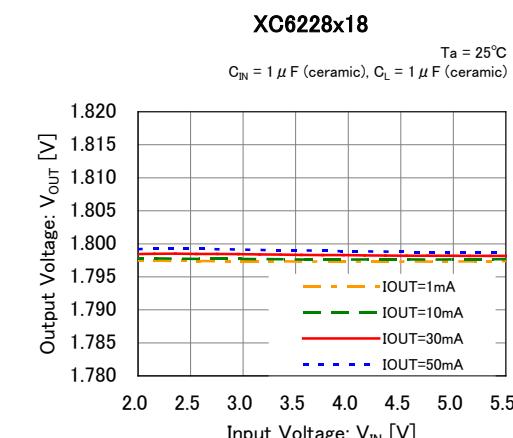
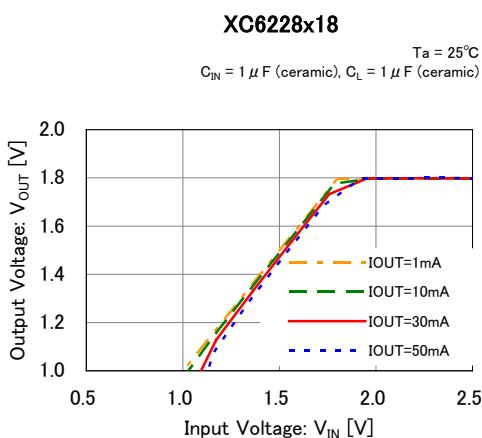
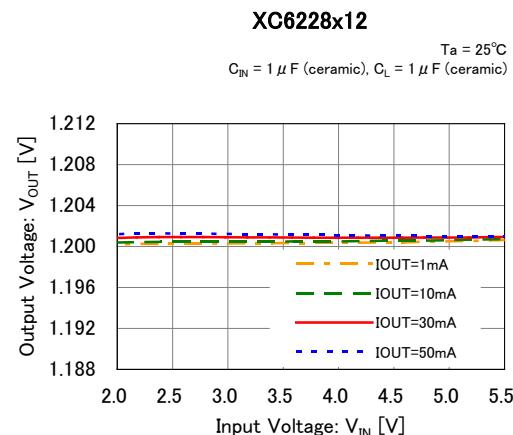
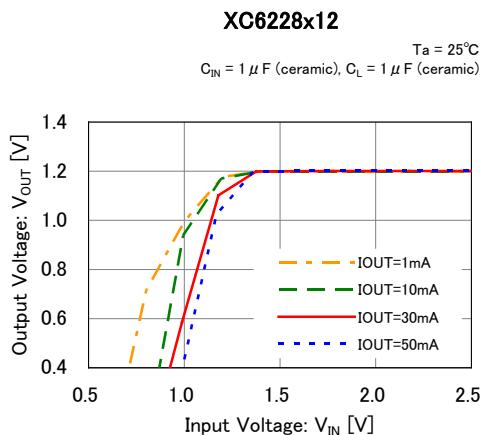
(1) Output Voltage vs. Output Current



XC6228D/H Series

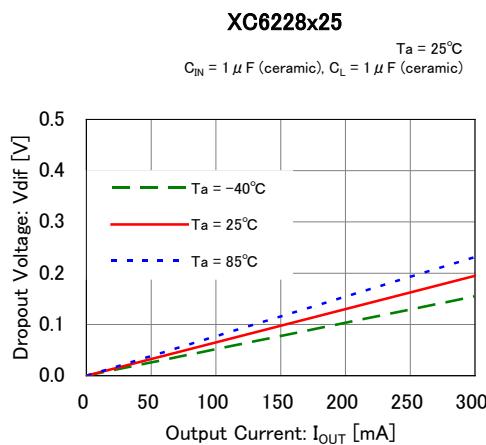
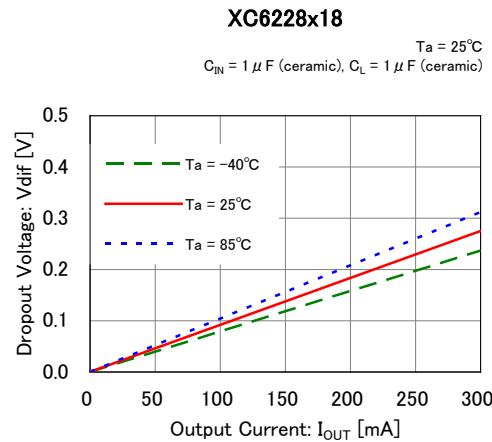
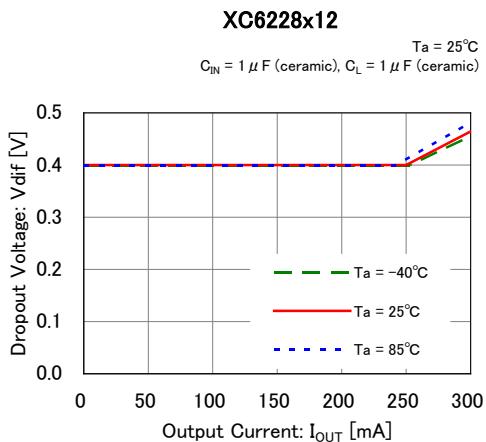
■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(2) Output Voltage vs. Input Voltage

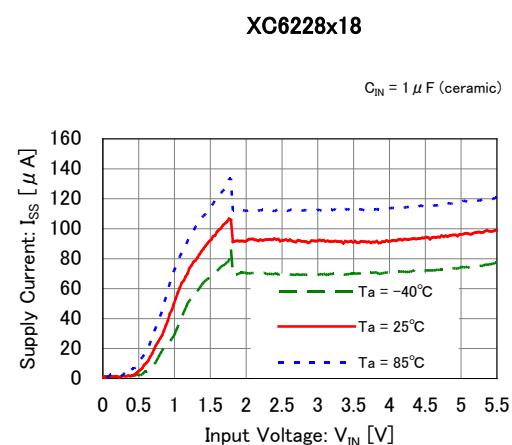
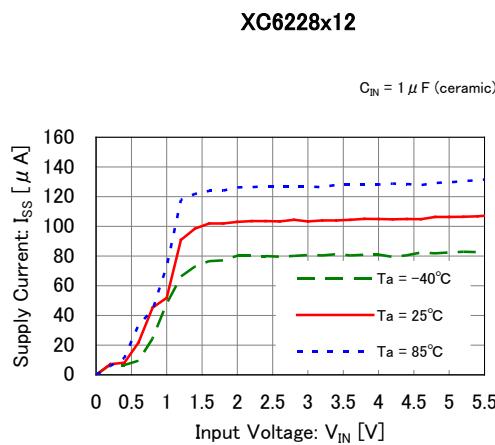


■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(3) Dropout Voltage vs. Output Current



(4) Supply Current vs. Input Voltage

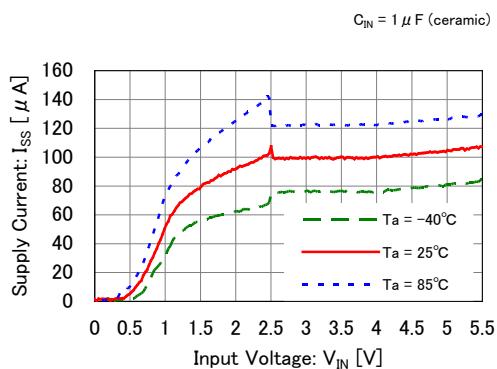


XC6228D/H Series

■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(4) Supply Current vs. Input Voltage (Continued)

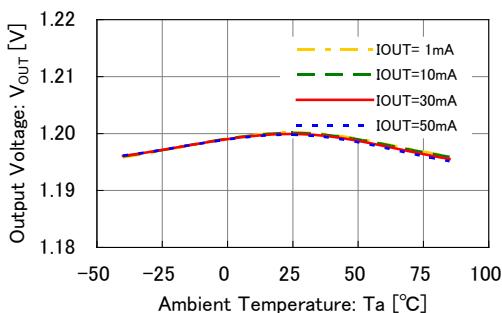
XC6228x25



(5) Output Voltage vs. Ambient Temperature

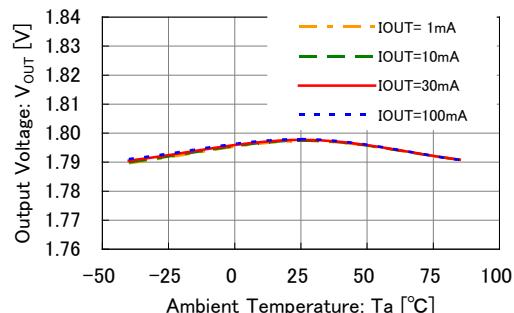
XC6228x12

$V_{IN} = 2.2V$
 $C_{IN} = 1 \mu F$ (ceramic), $C_L = 1 \mu F$ (ceramic)



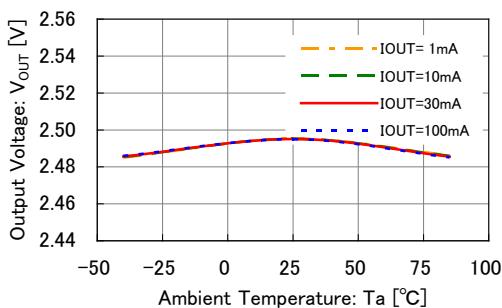
XC6228x18

$V_{IN} = 2.8V$
 $C_{IN} = 1 \mu F$ (ceramic), $C_L = 1 \mu F$ (ceramic)



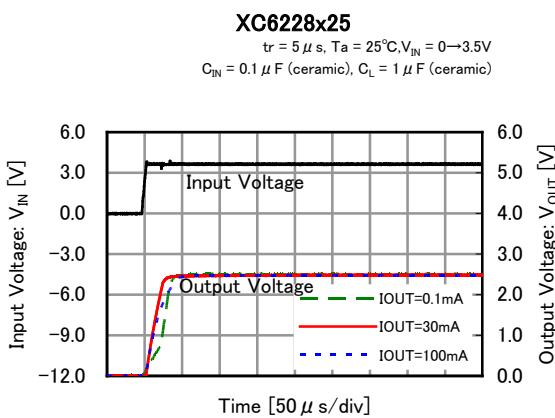
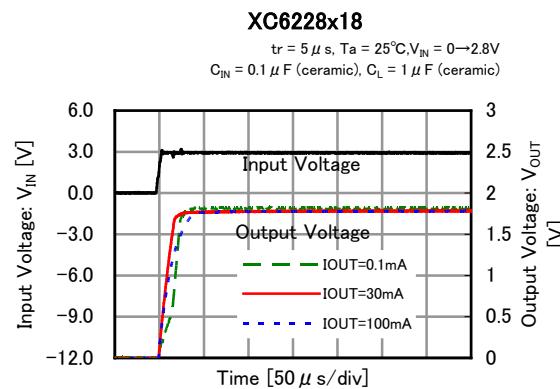
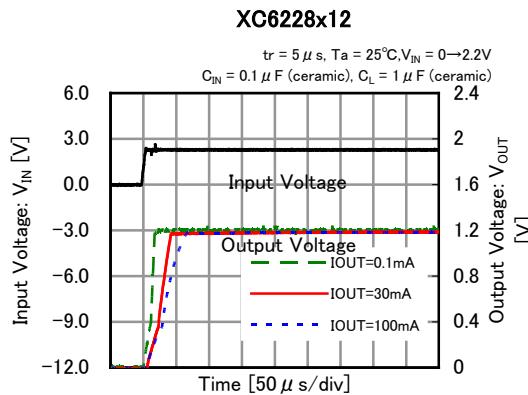
XC6228x25

$V_{IN} = 3.5V$
 $C_{IN} = 1 \mu F$ (ceramic), $C_L = 1 \mu F$ (ceramic)

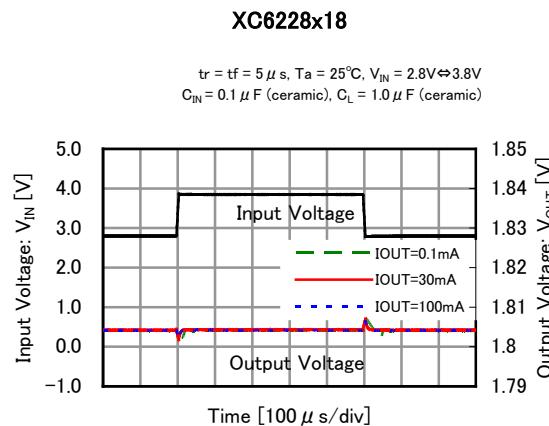
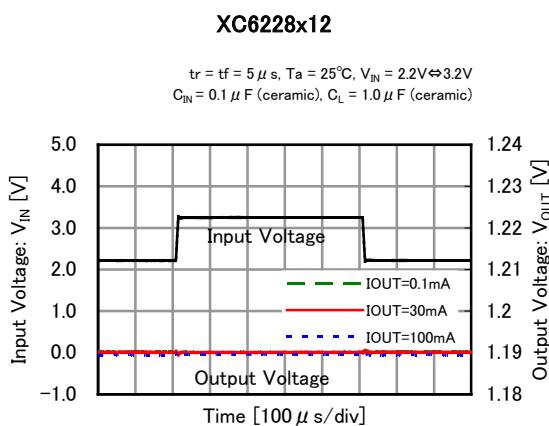


■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(6) Rising Response Time



(7) Input Transient Response



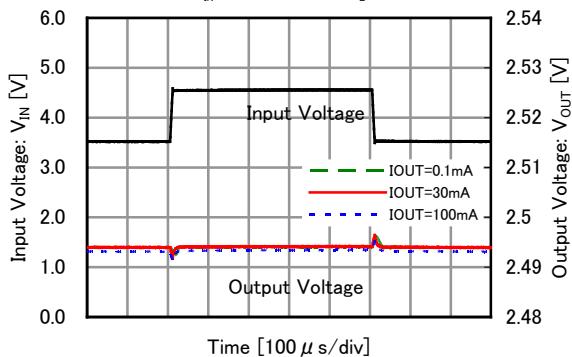
XC6228D/H Series

■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(7) Input Transient Response (Continued)

XC6228x25

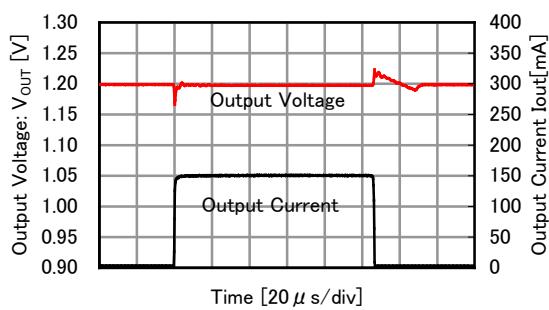
$t_r = t_f = 5 \mu s$, $T_a = 25^\circ C$, $V_{IN} = 3.5V \leftrightarrow 4.5V$
 $C_{IN} = 0.1 \mu F$ (ceramic), $C_L = 1.0 \mu F$ (ceramic)



(8) Load Transient Response ($t_r=t_f=0.5\mu s$)

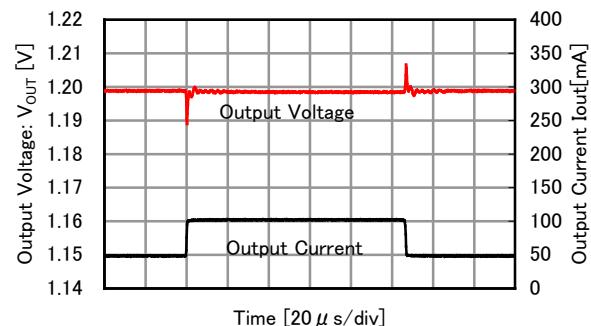
XC6228x12

$t_r = t_f = 0.5 \mu s$, $T_a = 25^\circ C$, $I_{OUT} = 1 \leftrightarrow 150\text{mA}$
 $V_{IN} = 2.2V$, $C_{IN} = 1 \mu F$ (ceramic), $C_L = 1 \mu F$ (ceramic)



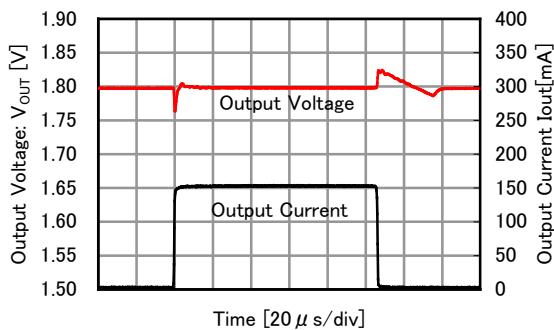
XC6228x12

$t_r = t_f = 0.5 \mu s$, $T_a = 25^\circ C$, $I_{OUT} = 50 \leftrightarrow 100\text{mA}$
 $V_{IN} = 2.2V$, $C_{IN} = 1 \mu F$ (ceramic), $C_L = 1 \mu F$ (ceramic)



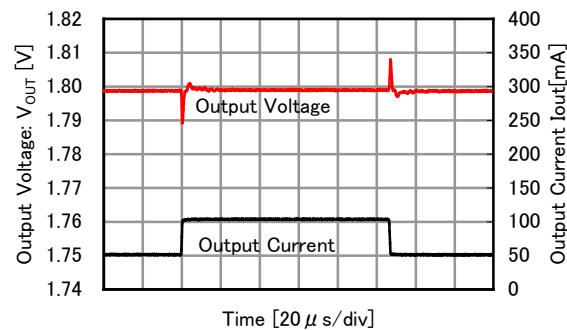
XC6228x18

$t_r = t_f = 0.5 \mu s$, $T_a = 25^\circ C$, $I_{OUT} = 1 \leftrightarrow 150\text{mA}$
 $V_{IN} = 2.8V$, $C_{IN} = 1 \mu F$ (ceramic), $C_L = 1 \mu F$ (ceramic)



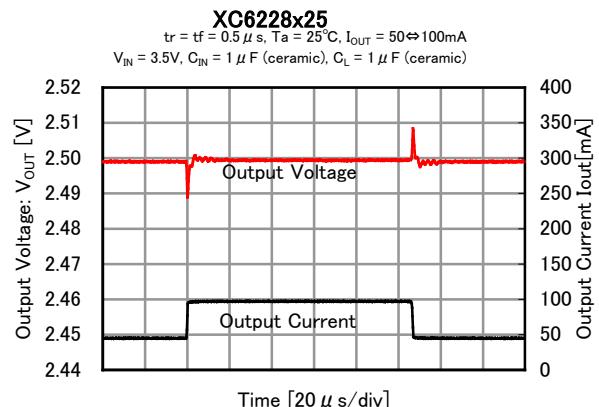
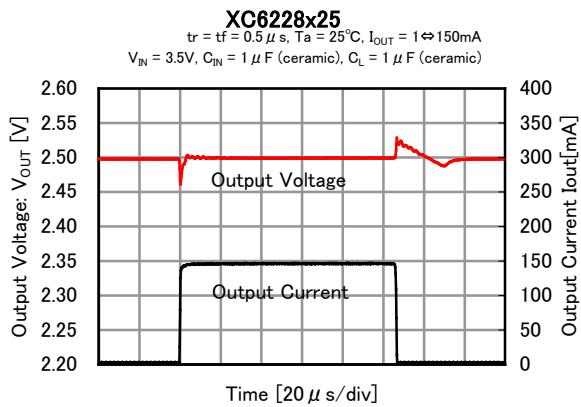
XC6228x18

$t_r = t_f = 0.5 \mu s$, $T_a = 25^\circ C$, $I_{OUT} = 50 \leftrightarrow 100\text{mA}$
 $V_{IN} = 2.8V$, $C_{IN} = 1 \mu F$ (ceramic), $C_L = 1 \mu F$ (ceramic)

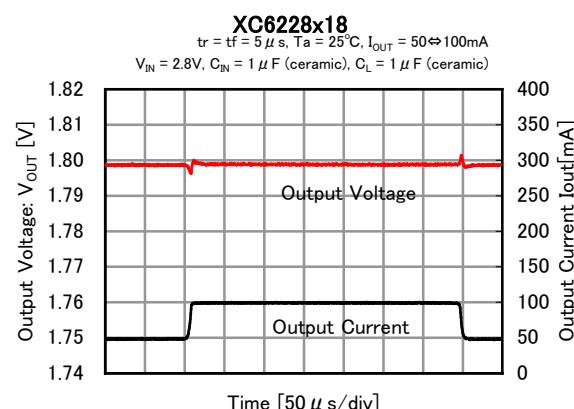
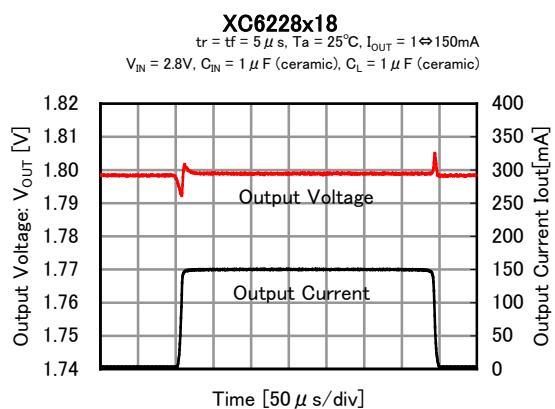
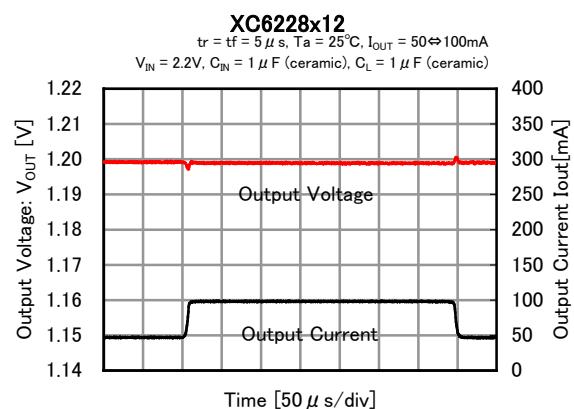
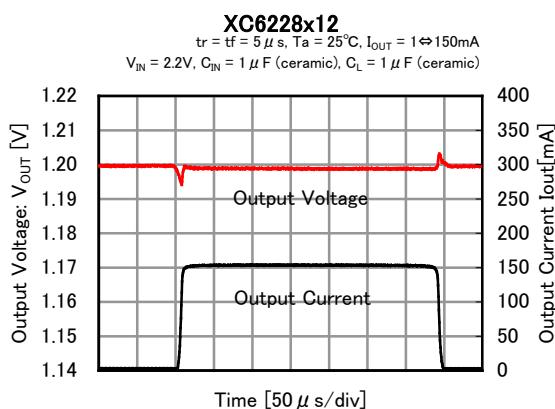


■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(8) Load Transient Response ($t_r=t_f=0.5\mu s$) (Continued)



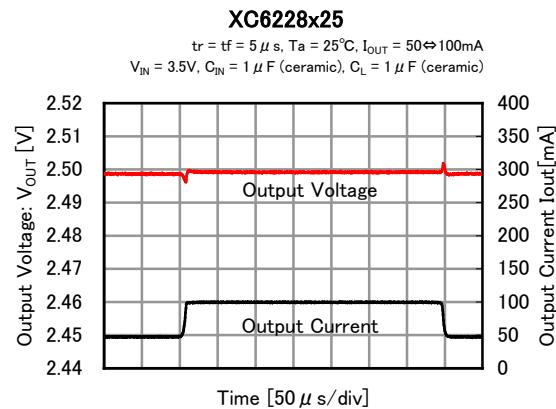
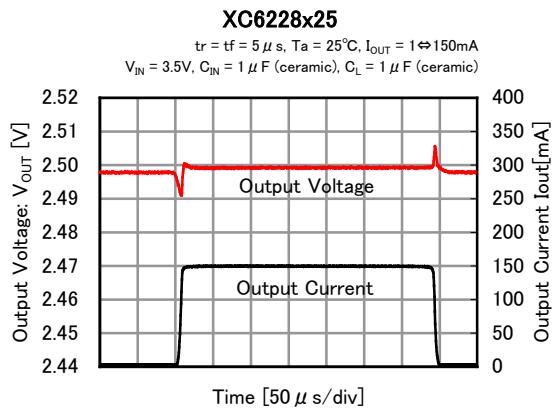
(9) Load Transient Response ($t_r=t_f=5\mu s$)



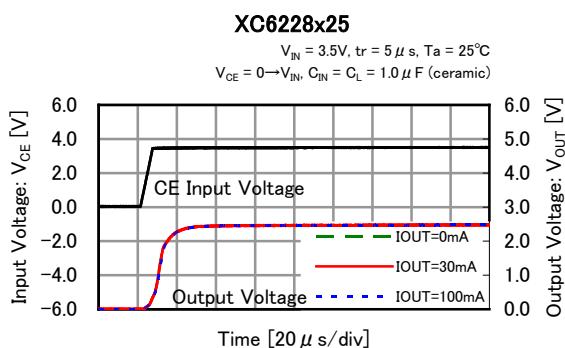
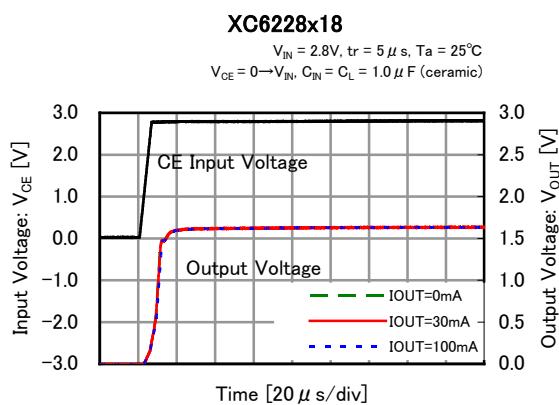
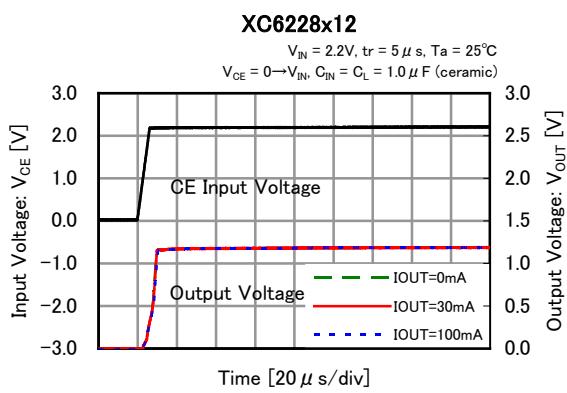
XC6228D/H Series

■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(9) Load Transient Response ($t_r=t_f=5\mu s$) (Continued)

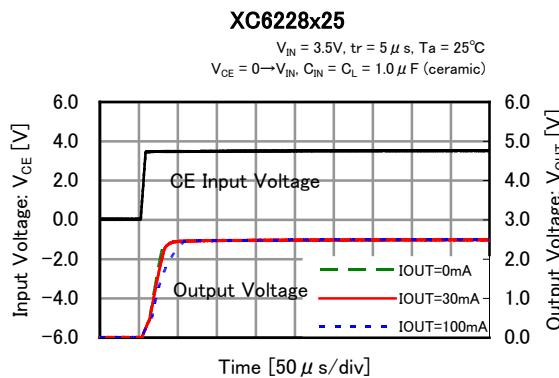
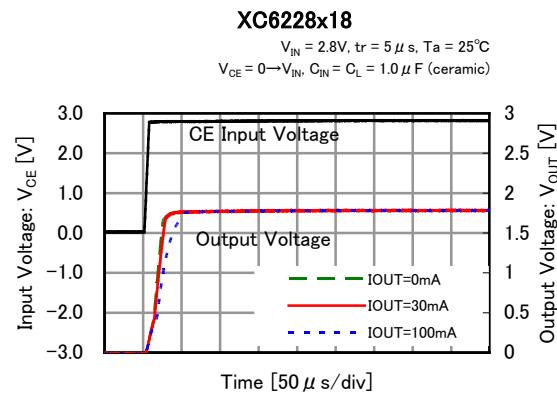
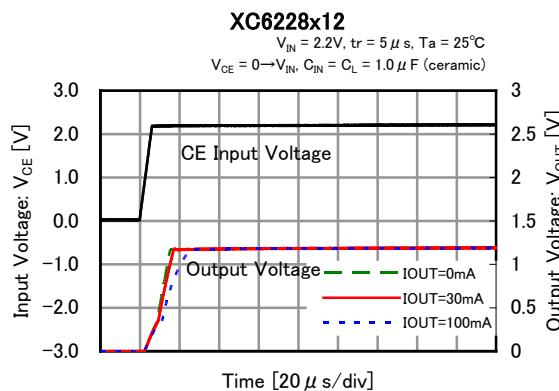


(10) CE Rising Response Time (Type D)

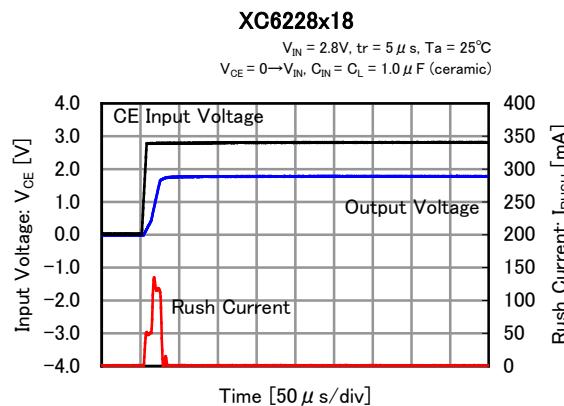
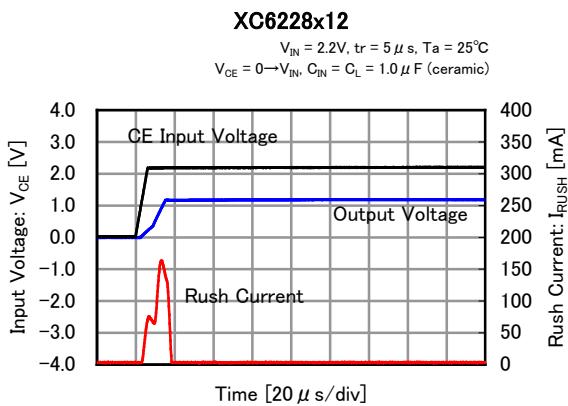


■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(11) CE Rising Response Time (Type H)



(12) Inrush Current Response Time (Type H)



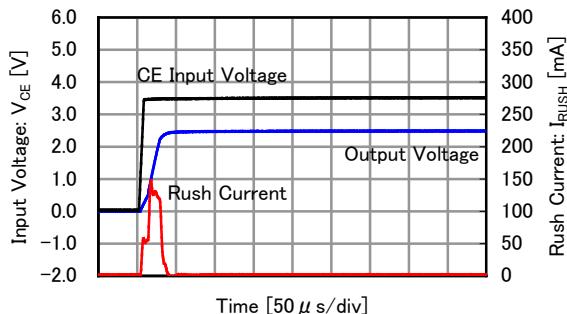
XC6228D/H Series

■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(12) Inrush Current Response Time (Type H)(Continued)

XC6228x25

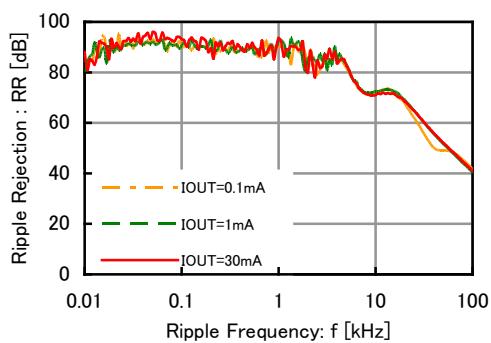
$V_{IN} = 3.5V$, $t_r = 5 \mu s$, $T_a = 25^\circ C$
 $V_{CE} = 0 \rightarrow V_{IN}$, $C_{IN} = C_L = 1.0 \mu F$ (ceramic)



(13) Ripple Rejection Rate

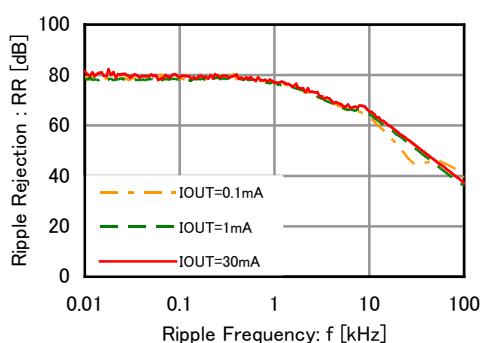
XC6228x12

$T_a = 25^\circ C$, $V_{IN} = 3.0VDC+0.5Vp-pAC$
 $C_{IN} = 0.1 \mu F$ (ceramic), $C_L = 1 \mu F$ (ceramic)



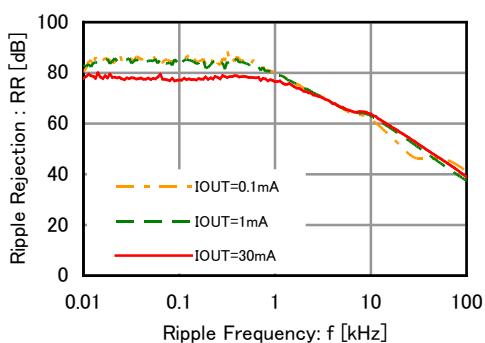
XC6228x18

$T_a = 25^\circ C$, $V_{IN} = 3.0VDC+0.5Vp-pAC$
 $C_{IN} = 0.1 \mu F$ (ceramic), $C_L = 1 \mu F$ (ceramic)



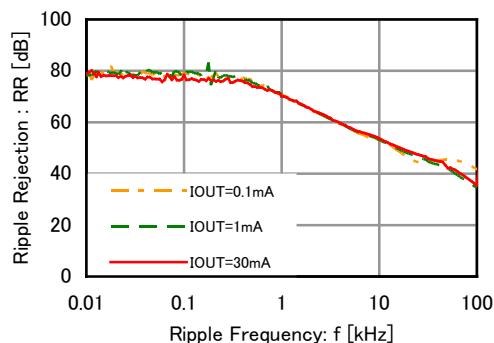
XC6228x25

$T_a = 25^\circ C$, $V_{IN} = 3.5VDC+0.5Vp-pAC$
 $C_{IN} = 0.1 \mu F$ (ceramic), $C_L = 1 \mu F$ (ceramic)



XC6228x33

$T_a = 25^\circ C$, $V_{IN} = 4.3VDC+0.5Vp-pAC$
 $C_{IN} = 0.1 \mu F$ (ceramic), $C_L = 1 \mu F$ (ceramic)



■PACKAGING INFORMATION

For the latest package information go to, www.torexsemi.com/technical-support/packages

PACKAGE	OUTLINE / LAND PATTERN	THERMAL CHARACTERISTICS
SOT-25J	SOT-25J PKG	SOT-25J Power Dissipation
USPQ-4B04	USPQ-4B04 PKG	USPQ-4B04 Power Dissipation

XC6228D/H Series

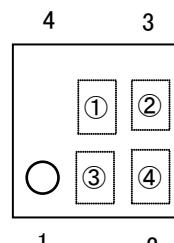
■ MARKING RULE

● USPQ-4B04

USPQ-4B04

① represents product series.

MARK	PRODUCT SERIES
1	XC6228*****-G



② represents products series, type of regulator and output voltage.

MARK	OUTPUT VOLTAGE (V)	PRODUCT SERIES
A	1.2	XC6228D12***-G
B	1.5	XC6228D15***-G
C	1.8	XC6228D18***-G
D	2.5	XC6228D25***-G
E	2.8	XC6228D28***-G
F	3.0	XC6228D30***-G
H	3.1	XC6228D31***-G
K	3.3	XC6228D33***-G
L	1.2	XC6228H12***-G
M	1.5	XC6228H15***-G
N	1.8	XC6228H18***-G
P	2.5	XC6228H25***-G
R	2.8	XC6228H28***-G
S	3.0	XC6228H30***-G
T	3.1	XC6228H31***-G
U	3.3	XC6228H33***-G

③④ represents production lot number.

01 to 09, 0A to 0Z, 11 to 9Z, A1 to A9, AA to AZ, B1 to ZZ in order.

(G, I, J, O, Q, W excepted)

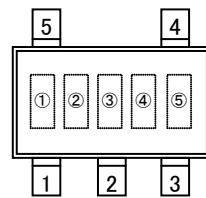
*No character inversion used.

■ MARKING RULE (Continued)

● SOT-25J

① represents product series.

MARK	PRODUCT SERIES
9	XC6228*****-G



② represents type of regulator and combination of output voltage.

MARK	PRODUCT SERIES
P	XC6228D*****-G
3	XC6228H*****-G

SOT-25J
(TOP VIEW)

MARK	OUTPUT VOLTAGE (V)	PRODUCT SERIES
2	1.2	XC6228*12***-G
5	1.5	XC6228*15***-G
8	1.8	XC6228*18***-G
F	2.5	XC6228*25***-G
L	2.8	XC6228*28***-G
N	3.0	XC6228*30***-G
P	3.1	XC6228*31***-G
S	3.3	XC6228*33***-G

④⑤ represents production lot number.

01 to 09, 0A to 0Z, 11 to 9Z, A1 to A9, AA to AZ, B1 to ZZ in order.

(G, I, J, O, Q, W excepted)

*No character inversion used.

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